

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013 PHONE: (215) 631-9840 FAX: (215) 631-9855

# MS2575

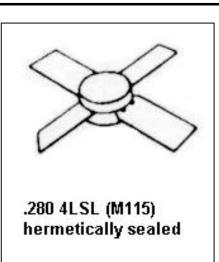
## RF & MICROWAVE TRANSISTORS AVIONICS APPLICATIONS

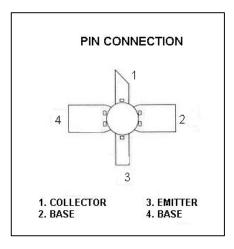
## **Features**

- 1025-1150 MHz
- GOLD METALLIZATION
- INPUT MATCHED
- INFINITE VSWR CAPABILITY @ RATED CONDITIONS
- P<sub>OUT</sub> = 35 W MINIMUM
- G<sub>P</sub> = 10.7 dB

## **DESCRIPTION:**

The MS2575 is a medium power Class C transistor designed specifically for pulsed L-Band avionics applications. Low RF thermal resistance and computerized automatic wire bonding techniques ensure high reliability and product consistency. The MS2575 is housed in the IMPAC<sup>™</sup> package with internal input matching.





## **ABSOLUTE MAXIMUM RATINGS (Tcase = 25^{\circ}C)**

Symbol	Parameter	Value	Unit
P <sub>DISS</sub>	Power Dissipation	150	W
V <sub>CE</sub>	Collector-Emitter Bias Voltage	55	V
TJ	Junction Temperature	200	° C
Ι <sub>C</sub>	Device Current	3	Α
T <sub>STG</sub>	Storage Temperature	-65 to +200	°C

#### THERMAL DATA

R <sub>TH(J-C)</sub>	Junction-case Thermal Resistance	1.0	°C/W
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# **MS2575**

# ELECTRICAL SPECIFICATIONS (Tcase = $25^{\circ}$ C)

### STATIC

Symbol		Test Conditions		Value		
			Min.	Typ.	Max.	Unit
BV <sub>CBO</sub>	I <sub>c</sub> = 10 mA	I <sub>E</sub> = 0 mA	65			V
BV <sub>CER</sub>	I <sub>c</sub> = 10 mA	R <sub>BE</sub> = 10Ω	65			V
BV <sub>EBO</sub>	I <sub>E</sub> =1 mA	I <sub>c</sub> = 0 mA	3.5			V
I <sub>CES</sub>	V <sub>CE</sub> = 50 V				5.0	mA
HFE	$V_{CE} = 5 V$	l <sub>c</sub> = 500 mA	15		120	

### DYNAMIC

Symbol	Test Conditions	3		Value		
			Min.	Typ.	Max.	Unit
Ρουτ	f =1025 - 1150 MHz P <sub>IN</sub> = 3W	V <sub>CE</sub> =50V	35			W
ηc	f =1025 - 1150 MHz P <sub>IN</sub> = 3W	V <sub>CE</sub> =50V	43			%
G <sub>P</sub>	f =1025 - 1150 MHz P <sub>IN</sub> = 3W	V <sub>CE</sub> =50V	10.7			dB
Conditions	Pulse Width = 10 $\mu$ s Duty Cycle = 1	1%				

#### **IMPEDANCE DATA**

FREQ	<b>Ζ<sub>IN</sub>(</b> Ω)	$Z_{CL}(\Omega)$		
1025 MHz	2.6 + j8.3	7.7 + j2.0		
1090 MHz	2.8 + j8.7	7.1 + j1.0		
1150 MHz	3.2 + j4.4	6.5 — j0.5		

Pin = 3W Vce = 50V



**MS2575** 

## PACKAGE MECHANICAL DATA

PACKAGE STYLE M115

